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# STS01DTP06

### Dual NPN-PNP complementary Bipolar transistor

### **General features**

V <sub>CE(sat)</sub>	h <sub>FE</sub>	I <sub>C</sub>
0.35V	>100	1A

- High gain
- Low V<sub>CE(sat)</sub>
- Simplified circuit design
- Reduced component count

### Applications

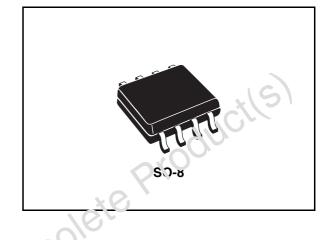
- Push-Pull or Totem-Pole configuration
- MOSFET and IGBT gate driving
- Motor, relay and solenoid driving

### Description

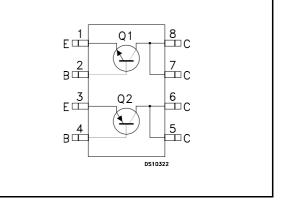
The STS01DTP06 is a Hybrid dual NPN-PNP complementary power bipolal transistor manufactured by using the latest low voltage planar techlogy. The STS01DTP06 is housed in dual island SO-8 package with separated terminals for higher assembly flexibility, specifically recommended to be used in Push-Pull or Totem Fole configuration as post IGBTs and MCSFS7 s driver.

### Order codes

Part Number	Marking	Package	Packing
STS01DTP06	S01DTP06	SO-8	Tape & reel



### Internal schematic diagram



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## 1 Electrical ratings

Table 1.	Absolute maximum ratings
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Symbol	Parameter	Va	Unit	
		NPN	PNP	
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	60	-60	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	30	-30	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	5	-5	v
۱ <sub>C</sub>	Collector current	3	-3	b x
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5ms)	6	-6	А
Ι <sub>Β</sub>	Base current	. 10	-1	А
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 1ms)	2	-2	А
P <sub>tot</sub>	Total dissipation at $T_c = 25^{\circ}C$ single	2	2	W
P <sub>tot</sub>	Total dissipation at $T_c = 25^{\circ}C$ couple	1.6		W
T <sub>stg</sub>	Storage temperature	o 150	°C	
TJ	Max. operating junction temperature	15	50	°C

# Table 2. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-amb</sub> 1	Therr ral resistance junction-ambientMax(Sincle operation)	62.5	°C/W
R ni-amb 1	Thermal resistance junction-ambient Max (Dual operation)	78	°C/W

When mounted on 1 inch square pad of 2 oz. copper,  $t \le 10$  sec.



#### **Electrical characteristics** 2

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$ 

Table J.									
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit			
I <sub>CBO</sub>	Collector cut-off current $(I_E = 0)$	V <sub>CB</sub> = 60V			0.1	μA			
I <sub>CEO</sub>	Collector cut-off current $(I_B = 0)$	V <sub>CE</sub> = 30V			1	μA			
I <sub>EBO</sub>	Emitter cut-off current $(I_{\rm C} = 0)$	V <sub>EB</sub> = 5V		(		μA			
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10mA	30	00		v			
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_{C} = 1A$ $I_{B} = 10 \text{ mA}$ $I_{C} = 2A$ $I_{E} = 100 \text{mA}$		0.35	1 0.7	V V			
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation voltage	I <sub>C</sub> = 1. I <sub>B</sub> = 10mA		0.85	1.1	V			
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$V_{CE} = 1A$ $V_{CE} = 2V$ $V_{CE} = 3A$ $V_{CE} = 2V$	100 30						

Table 3. Q1-NPN transistor electrical characteristics	Table 3.	Q1-NPN transistor electrical characteristics
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1. Pulsed: Pulse duration = (70 mc) Juty cycle  $\leq 1.5 \%$ 

 $(T_{case} = 25^{\circ}C \text{ un'ess planerwise specified})$ 

	Table 4.	G2-PNP transistor electrical characteristics					
	S∵mbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Obsole	I I <sub>CBO</sub>	Collector cut-off current $(I_E = 0)$	V <sub>CB</sub> = -60V			-0.1	μA
	I <sub>CEO</sub>	Collector cut-off current $(I_B = 0)$	V <sub>CE</sub> = -30V			-1	μA
	I <sub>EBO</sub>	Emitter cut-off current $(I_{\rm C} = 0)$	V <sub>EB</sub> = -5V			-1	μA
	V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = -10mA	-30			v
	V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_{C} = -1A$ $I_{B} = -10mA$ $I_{C} = -2A$ $I_{B} = -100mA$		-0.35	-1 -0.7	V V

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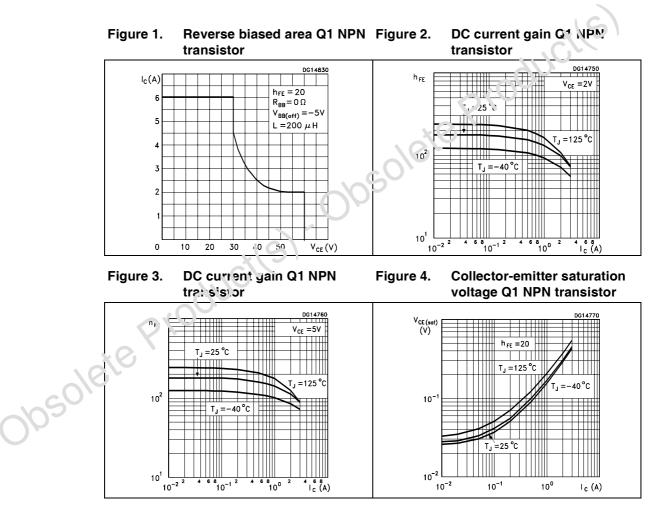


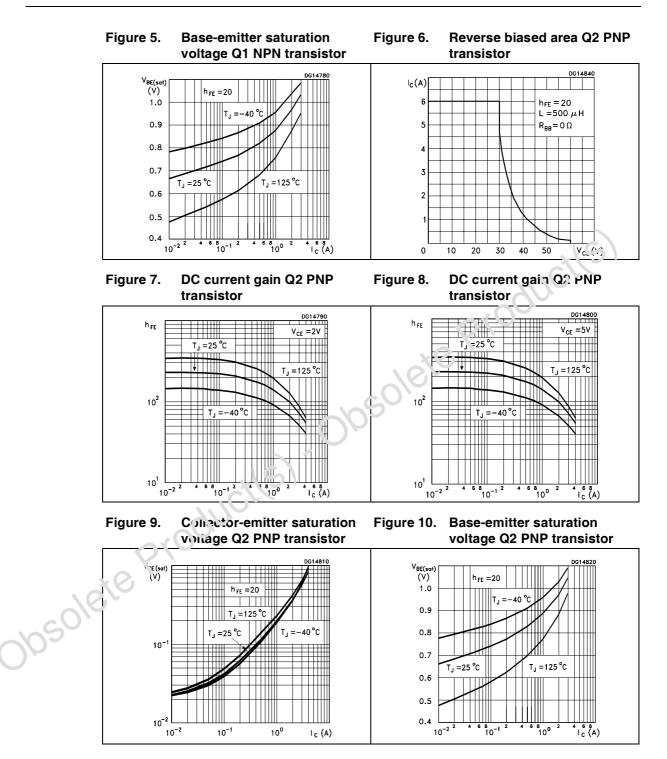
Symb	loc	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
V <sub>BE(sa</sub>	t) <sup>(1)</sup>	Base-emitter saturation voltage	I <sub>C</sub> = -1A	I <sub>B</sub> = -10mA		-0.85	-1.1	V
h <sub>FE</sub> (	[1)	DC current gain	I <sub>C</sub> = -1A I <sub>C</sub> = -3A	V <sub>CE</sub> = -2V V <sub>CE</sub> = -2V	100 30			

Table 4. Q2-PNP transistor electrical characteristics

1. Pulsed: Pulse duration = 300 ms, duty cycle  $\leq$  1.5 %

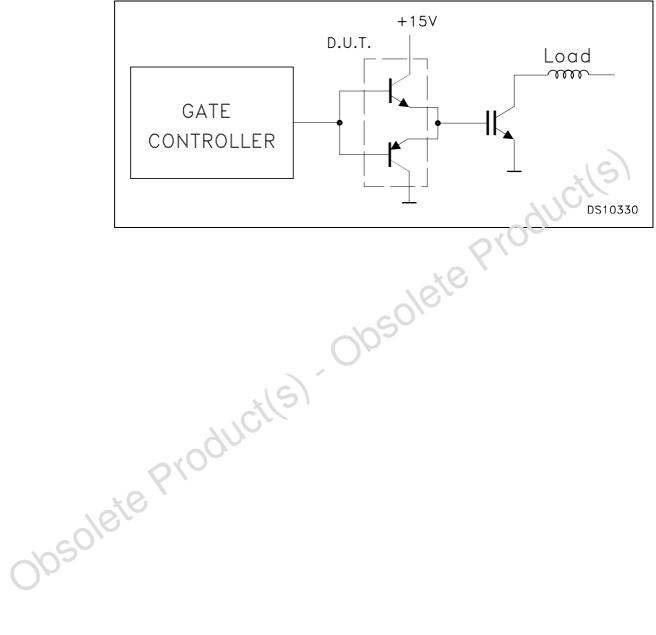
### 2.1 Electrical characteristics (curve)





### 2.2 Test circuits

#### Figure 11. Typical application



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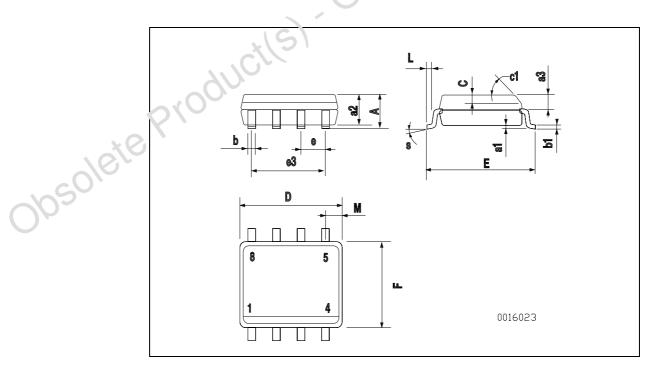
### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

obsolete Product(s). Obsolete Product(s)



ым	mm.			inch			
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А			1.75			0.068	
a1	0.1		0.25	0.003		0.009	
a2			1.65			0.064	
a3	0.65		0.85	0.025		0.033	
b	0.35		0.48	0.013		0.018	
b1	0.19		0.25	0.007		0.010	
С	0.25		0.5	0.010	. (	0.019	
c1		•	45	(typ.)	111		
D	4.8		5.0	0.188		0.196	
Е	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		3.81		. 0	0.150		
F	3.8		4.0	0.14		0.157	
L	0.4		1.27	0.015		0.050	
М			0.3			0.023	
S			8 (r	nax.)	•	•	



SO-8 MECHANICAL DATA



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### 4 Revision history

#### Table 5. Revision history

	Date	Revision	Changes
	22-Apr-2005	1	Initial release.
	22-Mar-2006	2	New template
	30-Mar-2006	3	The limit of current in figure number six has been modified from 6.5A to 6A.
obsole	tepro	Jucit	obsolete Productis

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